NSN 5961-00-134-7096

Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-134-7096 **Inclosure Material:** Metal **Overall Length:** Between 0.065 inches and 0.085 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-base, emitter open and 10.0 breakdown voltage, collector-to-emitter, base open and 4.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current and 1.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No